NSN 5962-01-310-7968

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
+0.0/+85.0 degrees celsius
End Application:
Forward card box assembly
Features Provided:
Burn in and monolithic and dynamic
Inclosure Material:
Silicon
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Case Outline Source And Designator:
D-2 mil-m-38510
Terminal Surface Treatment:
Solder
Memory Device Type:
Rom
Special Features:
65, 536 x 1 bit
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0